SLAS868A - JUNE 2012 - REVISED NOVEMBER 2012

MIXED SIGNAL MICROCONTROLLER

FEATURES

- Low Supply Voltage Range: 1.8 V to 3.6 V
- Ultra-Low Power Consumption
 - Active Mode: 220 µA at 1 MHz, 2.2 V
 - Standby Mode: 0.5 μA
 - Off Mode (RAM Retention): 0.1 μA
- Five Power-Saving Modes
- Ultra-Fast Wake-Up From Standby Mode in Less Than 1 µs
- 16-Bit RISC Architecture, 62.5-ns Instruction Cycle Time
- Basic Clock Module Configurations
 - Internal Frequencies up to 16 MHz With Four Calibrated Frequencies
 - Internal Very-Low-Power Low-Frequency (LF) Oscillator
 - 32-kHz Crystal
 - External Digital Clock Source
- One 16-Bit Timer_A With Three Capture/Compare Registers
- Up to 16 Touch-Sense Enabled I/O Pins
- Universal Serial Interface (USI) Supporting SPI and I2C
- Brownout Detector

- Serial Onboard Programming, No External Programming Voltage Needed, Programmable Code Protection by Security Fuse
- On-Chip Emulation Logic With Spy-Bi-Wire Interface
- Family Members are Summarized in Table 1
- Package Options
 - TSSOP: 14 Pin
- For Complete Module Descriptions, See the MSP430x2xx Family User's Guide (SLAU144)

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly and Test Site
- One Fabrication Site
- Available in Extended (-40°C to 85°C)
 Temperature Range (1)
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Custom temperature ranges available

DESCRIPTION

The Texas Instruments MSP430[™] family of ultra-low-power microcontrollers consist of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low-power modes is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that contribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 1 µs.

The MSP430G2302 series of microcontrollers are ultra-low-power mixed signal microcontrollers with built-in 16-bit timers, and up to 16 I/O touch sense enabled pins and built-in communication capability using the universal serial communication interface. For configuration details, see Table 1. Typical applications include low-cost sensor systems that capture analog signals, convert them to digital values, and then process the data for display or for transmission to a host system.

MA.

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Table 1. Available Options⁽¹⁾

Device	EEM	Flash (kB)	RAM (B)	Timer_A	ADC10 Channel	USI	CLOCK	1/0	Package Type
MSP430G2302IPW1REP	1	4	256	1x TA3	-	1	LF, DCO, VLO	10	14-TSSOP

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

Table 2. ORDERING INFORMATION(1)

T _A	PACKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING	VID NUMBER	
4000 to 0500	TOOOD DW	MSP430G2302IPW1EP	C0200ED	V(CQ/4QCQQ Q4VE	
–40°C to 85°C	TSSOP - PW	MSP430G2302IPW1REP	G2302EP	V62/12623-01XE	

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

SLAS868A - JUNE 2012-REVISED NOVEMBER 2012



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DEVICE PINOUTS

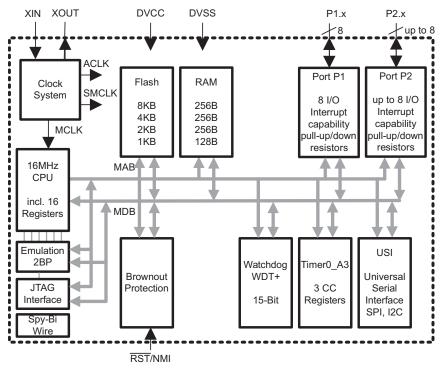
PW PACKAGE (TOP VIEW) DVCC 1 1 14 DVSS P1.0/TA0CLK/ACLK/A0 2 13 XIN/P2.6/TA0.1 P1.1/TA0.0/A1 3 12 XOUT/P2.7 P1.2/TA0.1/A2 4 11 DTEST/SBWTCK P1.3/ADC10CLK/A3/VREF-/VEREF- 5 10 RST/NMI/SBWTDIO P1.4/TA0.2/SMCLK/A4/VREF+/VEREF+/TCK 6 9 DP1.7/SDI/SDA/A7/TDO/TDI P1.5/TA0.0/SCLK/A5/TMS 1 7 8 DP1.6/TA0.1/SDO/SCL/A6/TDI/TCLK

NOTE: The pulldown resistors of port pins P2.0, P2.1, P2.2, P2.3, P2.4, and P2.5 should be enabled by setting P2REN.x = 1.



FUNCTIONAL BLOCK DIAGRAMS

Functional Block Diagram, MSP430G2302



NOTE: Port P2: Two pins are available on the 14-pin package option. Eight pins are available on the 20-pin package option.



TERMINAL FUNCTIONS

Table 3. Terminal Functions

TERMINAL			
NAME NO.		I/O	DESCRIPTION
NAME	PW14		
P1.0/			General-purpose digital I/O pin
TA0CLK/	0	1/0	Timer0_A, clock signal TACLK input
ACLK/	2	I/O	ACLK signal output
A0			ADC10 analog input A0
P1.1/			General-purpose digital I/O pin
TA0.0/	3	I/O	Timer0_A, capture: CCI0A input, compare: Out0 output
A1			ADC10 analog input A1
P1.2/			General-purpose digital I/O pin
TA0.1/	4	I/O	Timer0_A, capture: CCI1A input, compare: Out1 output
A2			ADC10 analog input A2
P1.3/			General-purpose digital I/O pin
ADC10CLK/	_		ADC10, conversion clock output
A3/	5	I/O	ADC10 analog input A3
VREF-/VEREF			ADC10 negative reference voltage
P1.4/			General-purpose digital I/O pin
TA0.2/			Timer0_A, capture: CCI2A input, compare: Out2 output
SMCLK/			SMCLK signal output
A4/	6	I/O	ADC10 analog input A4
VREF+/VEREF+/			ADC10 positive reference voltage
TCK			JTAG test clock, input terminal for device programming and test
P1.5/			General-purpose digital I/O pin
TA0.0/			Timer0_A, compare: Out0 output
A5/	7	I/O	ADC10 analog input A5
SCLK/			USI: clk input in I2C mode; clk in/output in SPI mode
TMS			JTAG test mode select, input terminal for device programming and test
P1.6/			General-purpose digital I/O pin
TA0.1/			Timer0_A, compare: Out1 output
A6/			ADC10 analog input A6
SDO/	8	I/O	USI: Data output in SPI mode
SCL/			USI: I2C clock in I2C mode
TDI/			JTAG test data input or test clock input during programming and test
TCLK			
P1.7/			General-purpose digital I/O pin
A7/			ADC10 analog input A7
SDI/	9	I/O	USI: Data input in SPI mode
SDA/			USI: I2C data in I2C mode
TDO/TDI ⁽¹⁾			JTAG test data output terminal or test data input during programming and test
XIN/			Input terminal of crystal oscillator
P2.6/	13	I/O	General-purpose digital I/O pin
TA0.1			Timer0_A, compare: Out1 output



Table 3. Terminal Functions (continued)

TERMINAL						
NAME	NO.	I/O	DESCRIPTION			
NAME	PW14					
XOUT/	12	I/O	Output terminal of crystal oscillator (2)			
P2.7	12	1/0	General-purpose digital I/O pin			
RST/			Reset			
NMI/	10	1	Nonmaskable interrupt input			
SBWTDIO/			Spy-Bi-Wire test data input/output during programming and test			
TEST/	11		Selects test mode for JTAG pins on Port 1. The device protection fuse is connected to TEST.			
SBWTCK	11		Spy-Bi-Wire test clock input during programming and test			
DVCC	1	NA	Supply voltage			
AVCC	NA	NA	Supply voltage			
DVSS	14	NA	Ground reference			
AVSS	NA	NA	Ground reference			
NC	-	NA	Not connected			
QFN Pad	-	NA	QFN package pad connection to VSS recommended.			

⁽²⁾ If XOUT/P2.7 is used as an input, excess current flows until P2SEL.7 is cleared. This is due to the oscillator output driver connection to this pad after reset.

SHORT-FORM DESCRIPTION

CPU

The MSP430™ CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator, respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

The instruction set consists of the original 51 instructions with three formats and seven address modes and additional instructions for the expanded address range. Each instruction can operate on word and byte data.

Instruction Set

The instruction set consists of 51 instructions with three formats and seven address modes. Each instruction can operate on word and byte data. Table 4 shows examples of the three types of instruction formats; Table 5 shows the address modes.



Table 4. Instruction Word Formats

FORMAT	EXAMPLE	OPERATION
Dual operands, source-destination	ADD R4,R5	R4 + R5 → R5
Single operands, destination only	CALL R8	$PC \rightarrow (TOS), R8 \rightarrow PC$
Relative jump, un/conditional	JNE	Jump-on-equal bit = 0

Table 5. Address Mode Descriptions⁽¹⁾

ADDRESS MODE	S	D	SYNTAX	EXAMPLE	OPERATION	
Register	✓	✓	MOV Rs,Rd	MOV R10,R11	R10 → R11	
Indexed	1	✓	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	$M(2+R5) \rightarrow M(6+R6)$	
Symbolic (PC relative)	1	✓	MOV EDE,TONI M(EDE) -		$M(EDE) \rightarrow M(TONI)$	
Absolute	1	✓	MOV &MEM,&TCDAT M(M		M(MEM) → M(TCDAT)	
Indirect	✓		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10) → M(Tab+R6)	
Indirect autoincrement	1		MOV @Rn+,Rm MOV @R10+,R11		M(R10) → R11 R10 + 2 → R10	
Immediate	✓		MOV #X,TONI MOV #45,TONI #45 → M		#45 → M(TONI)	

(1) S = source, D = destination



Operating Modes

The MSP430 devices have one active mode and five software selectable low-power modes of operation. An interrupt event can wake up the device from any of the low-power modes, service the request, and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode (AM)
 - All clocks are active
- Low-power mode 0 (LPM0)
 - CPU is disabled
 - ACLK and SMCLK remain active, MCLK is disabled
- Low-power mode 1 (LPM1)
 - CPU is disabled
 - ACLK and SMCLK remain active, MCLK is disabled
 - DCO's dc generator is disabled if DCO not used in active mode
- Low-power mode 2 (LPM2)
 - CPU is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator remains enabled
 - ACLK remains active
- Low-power mode 3 (LPM3)
 - CPU is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator is disabled
 - ACLK remains active
- Low-power mode 4 (LPM4)
 - CPU is disabled
 - ACLK is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator is disabled
 - Crystal oscillator is stopped

Interrupt Vector Addresses

The interrupt vectors and the power-up starting address are located in the address range 0FFFFh to 0FFC0h. The vector contains the 16-bit address of the appropriate interrupt handler instruction sequence.

If the reset vector (located at address 0FFFEh) contains 0FFFFh (for example, if flash is not programmed) the CPU goes into LPM4 immediately after power-up.

Table 6. Interrupt Sources, Flags, and Vectors

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-Up External Reset Watchdog Timer+ Flash key violation PC out-of-range ⁽¹⁾	PORIFG RSTIFG WDTIFG KEYV ⁽²⁾	Reset	0FFFEh	31, highest
NMI Oscillator fault Flash memory access violation	NMIIFG OFIFG ACCVIFG ⁽²⁾⁽³⁾	(non)-maskable (non)-maskable (non)-maskable	0FFFCh	30
			0FFFAh	29
			0FFF8h	28
			0FFF6h	27
Watchdog Timer+	WDTIFG	maskable	0FFF4h	26
Timer0_A3	TACCR0 CCIFG ⁽⁴⁾	maskable	0FFF2h	25
Timer0_A3	TACCR2 TACCR1 CCIFG. TAIFGTable 4 ⁽⁴⁾	maskable	0FFF0h	24
			0FFEEh	23
			0FFECh	22
USI	USIIFG, USISTTIFG ⁽²⁾⁽⁴⁾	maskable	0FFE8h	20
I/O Port P2 (up to eight flags)	P2IFG.0 to P2IFG.7 ⁽²⁾⁽⁴⁾	maskable	0FFE6h	19
I/O Port P1 (up to eight flags)	P1IFG.0 to P1IFG.7 ⁽²⁾⁽⁴⁾	maskable	0FFE4h	18
			0FFE2h	17
			0FFE0h	16
See (5)			0FFDEh to 0FFC0h	15 to 0, lowest

⁽¹⁾ A reset is generated if the CPU tries to fetch instructions from within the module register memory address range (0h to 01FFh) or from within unused address ranges.

⁽²⁾ Multiple source flags

^{(3) (}non)-maskable: the individual interrupt-enable bit can disable an interrupt event, but the general interrupt enable cannot.

⁽⁴⁾ Interrupt flags are located in the module.

⁽⁵⁾ The interrupt vectors at addresses 0FFDEh to 0FFC0h are not used in this device and can be used for regular program code if necessary.

Address

0



Special Function Registers (SFRs)

7

Most interrupt and module enable bits are collected into the lowest address space. Special function register bits not allocated to a functional purpose are not physically present in the device. Simple software access is provided with this arrangement.

Legend rw: Bit can be read and written.

rw-0,1: Bit can be read and written. It is reset or set by PUC.rw-(0,1): Bit can be read and written. It is reset or set by POR.

5

SFR bit is not present in device.

6

Table 7. Interrupt Enable Register 1 and 2

2

00h			ACCVIE	NMIIE			OFIE	WDTIE				
			rw-0	rw-0			rw-0	rw-0				
WDTIE		Watchdog Timer interrupt enable. Inactive if watchdog mode is selected. Active if Watchdog Timer is configured in interval timer mode.										
OFIE	Oscillato	Oscillator fault interrupt enable										
NMIIE	(Non)ma	skable interrupt	enable									
ACCVIE	Flash ac	Flash access violation interrupt enable										
Address	7	6	5	4	3	2	1	0				
01h												

Table 8. Interrupt Flag Register 1 and 2

Address	7	6	5	4	3	2	1	0			
02h				NMIIFG	RSTIFG	PORIFG	OFIFG	WDTIFG			
				rw-0	rw-(0)	rw-(1)	rw-1	rw-(0)			
WDTIFG											

OFIFG Flag set on oscillator fault.

PORIFG Power-On Reset interrupt flag. Set on V_{CC} power-up.

RSTIFG External reset interrupt flag. Set on a reset condition at \overline{RST} /NMI pin in reset mode. Reset on V_{CC} power-up.

NMIIFG Set via RST/NMI pin

Address	7	6	5	4	3	2	1	0
03h								

Memory Organization

Table 9. Memory Organization

		MSP430G2302
Memory	Size	4kB
Main: interrupt vector	Flash	0xFFFF to 0xFFC0
Main: code memory	Flash	0xFFFF to 0xF000
Information memory	Size	256 Byte
	Flash	010FFh to 01000h
RAM	Size	256 B
		0x02FF to 0x0200
Peripherals	16-bit	01FFh to 0100h
	8-bit	0FFh to 010h
	8-bit SFR	0Fh to 00h

Flash Memory

The flash memory can be programmed via the Spy-Bi-Wire/JTAG port or in-system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and four segments of information memory (A to D) of 64 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A to D can be erased individually or as a group with segments 0 to n. Segments A to D are also called *information memory*.
- Segment A contains calibration data. After reset, segment A is protected against programming and erasing. It
 can be unlocked, but care should be taken not to erase this segment if the device-specific calibration data is
 required.



Peripherals

Peripherals are connected to the CPU through data, address, and control buses and can be handled using all instructions. For complete module descriptions, see the MSP430x2xx Family User's Guide (SLAU144).

Oscillator and System Clock

The clock system is supported by the basic clock module that includes support for a 32768-Hz watch crystal oscillator, an internal very-low-power low-frequency oscillator, and an internal digitally controlled oscillator (DCO). The basic clock module is designed to meet the requirements of both low system cost and low power consumption. The internal DCO provides a fast turn-on clock source and stabilizes in less than 1 µs. The basic clock module provides the following clock signals:

- Auxiliary clock (ACLK), sourced either from a 32768-Hz watch crystal or the internal LF oscillator.
- · Main clock (MCLK), the system clock used by the CPU.
- Sub-Main clock (SMCLK), the sub-system clock used by the peripheral modules.

The DCO settings to calibrate the DCO output frequency are stored in the information memory segment A.

Calibration Data Stored in Information Memory Segment A

Calibration data is stored for both the DCO and for ADC10 organized in a tag-length-value structure.

Table 10. Tags Used by the ADC Calibration Tags

NAME	ADDRESS	VALUE	DESCRIPTION
TAG_DCO_30	0x10F6	0x01	DCO frequency calibration at V _{CC} = 3 V and T _A = 30°C at calibration
TAG_ADC10_1	0x10DA	0x10	ADC10_1 calibration tag
TAG_EMPTY	-	0xFE	Identifier for empty memory areas

Table 11. Labels Used by the ADC Calibration Tags

LABEL	CONDITION AT CALIBRATION / DESCRIPTION	SIZE	ADDRESS OFFSET
CAL_ADC_25T85	INCHx = 0x1010, REF2_5 = 1, T _A = 85°C	word	0x0010
CAL_ADC_25T30	INCHx = 0x1010, REF2_5 = 1, T _A = 30°C	word	0x000E
CAL_ADC_25VREF_FACTOR	REF2_5 = 1, $T_A = 30^{\circ}C$, $I_{(VREF+)} = 1 \text{ mA}$	word	0x000C
CAL_ADC_15T85	INCHx = 0x1010, REF2_5 = 0, T _A = 85°C	word	0x000A
CAL_ADC_15T30	INCHx = 0x1010, REF2_5 = 0, T _A = 30°C	word	0x0008
CAL_ADC_15VREF_FACTOR	REF2_5 = 0, $T_A = 30^{\circ}C$, $I_{(VREF+)} = 0.5$ mA	word	0x0006
CAL_ADC_OFFSET	External VREF = 1.5 V, f _(ADC10CLK) = 5 MHz	word	0x0004
CAL_ADC_GAIN_FACTOR	External VREF = 1.5 V, f _(ADC10CLK) = 5 MHz	word	0x0002
CAL_BC1_1MHz	-	byte	0x0009
CAL_DCO_1MHz	-	byte	0x00008
CAL_BC1_8MHz	-	byte	0x0007
CAL_DCO_8MHz	-	byte	0x0006
CAL_BC1_12MHz	-	byte	0x0005
CAL_DCO_12MHz		byte	0x0004
CAL_BC1_16MHz	-	byte	0x0003
CAL_DCO_16MHz	-	byte	0x0002

Main DCO Characteristics

- All ranges selected by RSELx overlap with RSELx + 1: RSELx = 0 overlaps RSELx = 1, ... RSELx = 14 overlaps RSELx = 15.
- DCO control bits DCOx have a step size as defined by parameter S_{DCO}.
- Modulation control bits MODx select how often f_{DCO(RSEL,DCO+1)} is used within the period of 32 DCOCLK cycles. The frequency f_{DCO(RSEL,DCO)} is used for the remaining cycles. The frequency is an average equal to:

$$f_{average} = \frac{32 \times f_{DCO(RSEL,DCO)} \times f_{DCO(RSEL,DCO+1)}}{MOD \times f_{DCO(RSEL,DCO)} + (32 - MOD) \times f_{DCO(RSEL,DCO+1)}}$$

Brownout

The brownout circuit is implemented to provide the proper internal reset signal to the device during power on and power off.

Digital I/O

There are two 8-bit I/O ports implemented:

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt condition(port P1 and port P2 only) is possible.
- Edge-selectable interrupt input capability for all the eight bits of port P1 and port P2, if available.
- · Read/write access to port-control registers is supported by all instructions.
- Each I/O has an individually programmable pullup/pulldown resistor.
- Each I/O has an individually programmable pin-oscillator enable bit to enable low-cost touch sensing.

WDT+ Watchdog Timer

The primary function of the watchdog timer (WDT+) module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be disabled or configured as an interval timer and can generate interrupts at selected time intervals.



Timer0 A3

Timer0_A3 is a 16-bit timer/counter with three capture/compare registers. Timer0_A3 can support multiple capture/compares, PWM outputs, and interval timing. Timer0_A3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

Table 12. Timer0_A3 Signal Connections⁽¹⁾

INPUT PIN NUMBER	DEVICE INPUT	MODULE INPUT	MODULE BLOCK	MODULE OUTPUT	OUTPUT PIN NUMBER
PW14	SIGNAL	NAME	SIGNAL		PW14
P1.0-2	TACLK	TACLK			
	ACLK	ACLK	T:	N/A	
	SMCLK	SMCLK	Timer	NA	
PinOsc		INCLK			
P1.1-3	TA0.0	CCI0A			P1.1-3
	ACLK	CCI0B	0000	TAG	P1.5-7
	V _{SS}	GND	CCR0	TA0	
	V _{CC}	V _{CC}	-		
P1.2-4	TA0.1	CCI1A			P1.2-4
	CAOUT	CCI1B	0004	TA4	P1.6-8
	V _{SS}	GND	CCR1	TA1	P2.6-13
	V _{CC}	V _{CC}			
P1.4-6	TA0.2	CCI2A			P1.4-6
PinOsc	TA0.2	CCI2B	0000	T40	
	V _{SS}	GND	CCR2	TA2	
	V _{CC}	V _{CC}	1		

⁽¹⁾ Only one pin-oscillator must be enabled at a time.

USI

The universal serial interface (USI) module is used for serial data communication and provides the basic hardware for synchronous communication protocols like SPI and I2C.

Peripheral File Map

Table 13. Peripherals With Word Access

MODULE	REGISTER DESCRIPTION	REGISTER NAME	OFFSET
Timer0_A3	Capture/compare register	TACCR2	0176h
	Capture/compare register	TACCR1	0174h
	Capture/compare register	TACCR0	0172h
	Timer_A register	TAR	0170h
	Capture/compare control	TACCTL2	0166h
	Capture/compare control	TACCTL1	0164h
	Capture/compare control	TACCTL0	0162h
	Timer_A control	TACTL	0160h
	Timer_A interrupt vector	TAIV	012Eh
Flash Memory	Flash control 3	FCTL3	012Ch
	Flash control 2	FCTL2	012Ah
	Flash control 1	FCTL1	0128h
Watchdog Timer+	Watchdog/timer control	WDTCTL	0120h



Table 14. Peripherals With Byte Access

MODULE	REGISTER DESCRIPTION	REGISTER NAME	OFFSET
USI	USI control 0	USICTL0	078h
	USI control 1	USICTL1	079h
	USI clock control	USICKCTL	07Ah
	USI bit counter	USICNT	07Bh
	USI shift register	USISR	07Ch
Basic Clock System+	Basic clock system control 3	BCSCTL3	053h
	Basic clock system control 2	BCSCTL2	058h
	Basic clock system control 1	BCSCTL1	057h
	DCO clock frequency control	DCOCTL	056h
Port P2	Port P2 selection 2	P2SEL2	042h
	Port P2 resistor enable	P2REN	02Fh
	Port P2 selection	P2SEL	02Eh
	Port P2 interrupt enable	P2IE	02Dh
	Port P2 interrupt edge select	P2IES	02Ch
	Port P2 interrupt flag	P2IFG	02Bh
	Port P2 direction	P2DIR	02Ah
	Port P2 output	P2OUT	029h
	Port P2 input	P2IN	028h
Port P1	Port P1 selection 2	P1SEL2	041h
	Port P1 resistor enable	P1REN	027h
	Port P1 selection	P1SEL	026h
	Port P1 interrupt enable	P1IE	025h
	Port P1 interrupt edge select	P1IES	024h
	Port P1 interrupt flag	P1IFG	023h
	Port P1 direction	P1DIR	022h
	Port P1 output	P1OUT	021h
	Port P1 input	P1IN	020h
Special Function	SFR interrupt flag 2	IFG2	003h
	SFR interrupt flag 1	IFG1	002h
	SFR interrupt enable 2	IE2	001h
	SFR interrupt enable 1	IE1	000h



SLAS868A - JUNE 2012-REVISED NOVEMBER 2012

Absolute Maximum Ratings⁽¹⁾

Voltage applied at V _{CC} to V _{SS}		–0.3 V to 4.1 V
Voltage applied to any pin ⁽²⁾		-0.3 V to V _{CC} + 0.3 V
Diode current at any device pin		±2 mA
Ct	Unprogrammed device	-55°C to 150°C
Storage temperature range, T _{stg} (3)	Programmed device	−55°C to 150°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltages referenced to V_{SS}. The JTAG fuse-blow voltage, V_{FB}, is allowed to exceed the absolute maximum rating. The voltage is applied to the TEST pin when blowing the JTAG fuse.
- Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

Thermal Information

	THERMAL METRIC	PW	UNITS
		14 PINS	
θ_{JA}	Junction-to-ambient thermal resistance ⁽¹⁾	98.7	
θ_{JCtop}	Junction-to-case (top) thermal resistance (2)	26.8	
θ_{JB}	Junction-to-board thermal resistance ⁽³⁾	41.2	00044
ΨЈТ	Junction-to-top characterization parameter ⁽⁴⁾	1.1	°C/W
ΨЈВ	Junction-to-board characterization parameter ⁽⁵⁾	40.5	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance (6)	N/A	

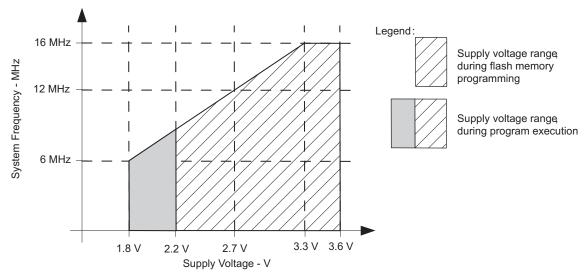
- (1) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDECstandard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
\/	Supply voltage	During program execution	1.8		3.6	V
V _{CC}	Supply voltage	During flash programming/erase	2.2		3.6	V
V_{SS}	Supply voltage			0		V
T_A	Operating free-air temperature		-40		85	°C
		V _{CC} = 1.8 V, Duty cycle = 50% ± 10%	dc		6	
f _{SYSTEM}	Processor frequency (maximum MCLK frequency using the USART module) (1)(2)	$V_{CC} = 2.7 \text{ V},$ Duty cycle = 50% ± 10%	dc		12	MHz
		V _{CC} = 3.3 V, Duty cycle = 50% ± 10%	dc		16	

- (1) The MSP430 CPU is clocked directly with MCLK. Both the high and low phase of MCLK must not exceed the pulse width of the specified maximum frequency.
- (2) Modules might have a different maximum input clock specification. See the specification of the respective module in this data sheet.



Note: Minimum processor frequency is defined by system clock. Flash program or erase operations require a minimum V_{CC} of 2.2 V.

Figure 1. Safe Operating Area



Electrical Characteristics

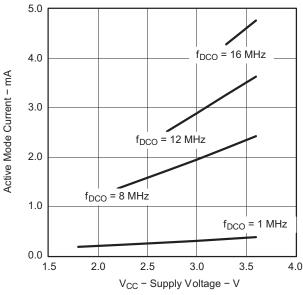
Active Mode Supply Current Into V_{CC} Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1)(2)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
	$f_{DCO} = f_{MCLK} = f_{SMCLK} = 1 \text{ MHz},$	2.2 V		220			
I _{AM,1MHz}	Active mode (AM) current (1 MHz)	f _{ACLK} = 32768 Hz, Program executes in flash, BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, CPUOFF = 0, SCG0 = 0, SCG1 = 0, OSCOFF = 0	3 V		320	400	μА

- All inputs are tied to 0 V or to V_{CC} . Outputs do not source or sink any current. The currents are characterized with a Micro Crystal CC4V-T1A SMD crystal with a load capacitance of 9 pF. The internal and external load capacitance is chosen to closely match the required 9 pF.

Typical Characteristics – Active Mode Supply Current (Into V_{CC})





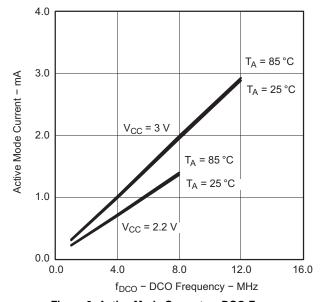


Figure 3. Active Mode Current vs DCO Frequency



Low-Power Mode Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1) (2)

Р	ARAMETER	TEST CONDITIONS	T _A	V _{cc}	MIN	TYP	MAX	UNIT
I _{LPM0,1MHz}	Low-power mode 0 (LPM0) current ⁽³⁾	$\begin{array}{l} f_{MCLK} = 0 \text{ MHz}, \\ f_{SMCLK} = f_{DCO} = 1 \text{ MHz}, \\ f_{ACLK} = 32768 \text{ Hz}, \\ BCSCTL1 = CALBC1_1MHZ, \\ DCOCTL = CALDCO_1MHZ, \\ CPUOFF = 1, SCG0 = 0, SCG1 = 0, \\ OSCOFF = 0 \end{array}$	25°C	2.2 V		55		μΑ
I _{LPM2}	Low-power mode 2 (LPM2) current ⁽⁴⁾	$\begin{split} &f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}, \\ &f_{DCO} = 1 \text{ MHz}, \\ &f_{ACLK} = 32768 \text{ Hz}, \\ &BCSCTL1 = CALBC1_1MHZ, \\ &DCOCTL = CALDCO_1MHZ, \\ &CPUOFF = 1, SCG0 = 0, SCG1 = 1, \\ &OSCOFF = 0 \end{split}$	25°C	2.2 V		22		μΑ
I _{LPM3,LFXT1}	Low-power mode 3 (LPM3) current ⁽⁴⁾	$ \begin{aligned} f_{DCO} &= f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}, \\ f_{ACLK} &= 32768 \text{ Hz}, \\ CPUOFF &= 1, \text{ SCG0} = 1, \text{ SCG1} = 1, \\ OSCOFF &= 0 \end{aligned} $	25°C	2.2 V		0.7	1.0	μΑ
I _{LPM3,VLO}	Low-power mode 3 current, (LPM3) ⁽⁴⁾	$ \begin{aligned} f_{DCO} &= f_{MCLK} = f_{SMCLK} = 0 \text{ MHz,} \\ f_{ACLK} &\text{from internal LF oscillator (VLO),} \\ CPUOFF &= 1, SCG0 = 1, SCG1 = 1, \\ OSCOFF &= 0 \end{aligned} $	25°C	2.2 V		0.5	0.7	μΑ
		$f_{DCO} = f_{MCLK} = f_{SMCLK} = 0 \text{ MHz},$	25°C	2.2 V		0.1	0.5	μΑ
I _{LPM4}	Low-power mode 4 (LPM4) current ⁽⁵⁾	f _{ACLK} = 0 Hz, CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 1	85°C	2.2 V		0.8	1.5	μΑ

- (1) All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.
- (2) The currents are characterized with a Micro Crystal CC4V-T1A SMD crystal with a load capacitance of 9 pF.
- (3) Current for brownout and WDT clocked by SMCLK included.
- (4) Current for brownout and WDT clocked by ACLK included.
- (5) Current for brownout included.

Typical Characteristics Low-Power Mode Supply Currents

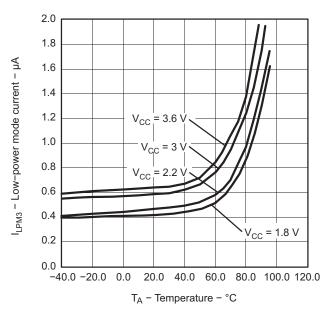


Figure 4. LPM3 Current vs Temperature

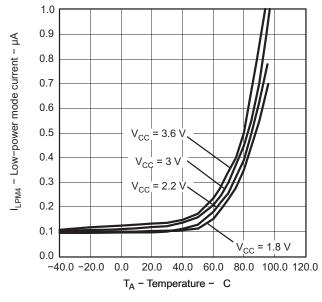


Figure 5. LPM4 Current vs Temperature

Schmitt-Trigger Inputs – Ports Px⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
V	Desitive going input threshold voltage			0.45 V _{CC}		0.75 V _{CC}	V
V _{IT+}	Positive-going input threshold voltage		3 V	1.35		2.25	V
V	Negative going input threshold voltage			0.25 V _{CC}		0.55 V _{CC}	V
V_{IT-}	Negative-going input threshold voltage		3 V	0.75		1.65	V
V_{hys}	Input voltage hysteresis (V _{IT+} – V _{IT-})		3 V	0.3		1	V
R _{Pull}	Pullup/pulldown resistor	For pullup: V _{IN} = V _{SS} For pulldown: V _{IN} = V _{CC}	3 V	20	35	50	kΩ
Cı	Input capacitance	$V_{IN} = V_{SS}$ or V_{CC}			5		pF

⁽¹⁾ An external signal sets the interrupt flag every time the minimum interrupt pulse width t_(int) is met. It may be set even with trigger signals shorter than t_(int).

Leakage Current - Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN MAX	UNIT
I _{lkg(Px.x)}	High-impedance leakage current	See ⁽¹⁾ and ⁽²⁾	3 V	±50	nA

The leakage current is measured with V_{SS} or V_{CC} applied to the corresponding pin(s), unless otherwise noted.

Outputs – Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	$I_{(OHmax)} = -6 \text{ mA}^{(1)}$	3 V	Vo	_{CC} – 0.3		٧
V _{OL}	Low-level output voltage	$I_{(OLmax)} = 6 \text{ mA}^{(1)}$	3 V	Vs	_{SS} + 0.3		V

The maximum total current, I_(OHmax) and I_(OLmax), for all outputs combined should not exceed ±48 mA to hold the maximum voltage drop specified.

Output Frequency – Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN TYP MAX	UNIT
$f_{Px.y}$	Port output frequency (with load)	Px.y, $C_L = 20 \text{ pF}$, $R_L = 1 \text{ k}\Omega^{(1)}$ (2)	3 V	12	MHz
f _{Port CLK}	Clock output frequency	$Px.y, C_L = 20 pF^{(2)}$	3 V	16	MHz

A resistive divider with two 0.5-kΩ resistors between V_{CC} and V_{SS} is used as load. The output is connected to the center tap of the divider.

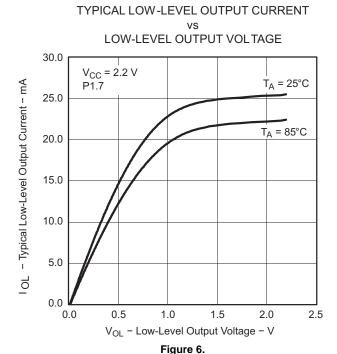
21

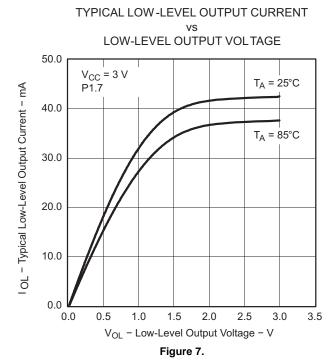
⁽²⁾ The leakage of the digital port pins is measured individually. The port pin is selected for input, and the pullup/pulldown resistor is disabled.

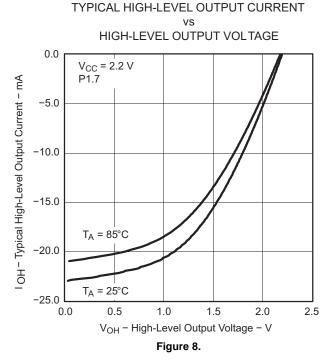
⁽²⁾ The output voltage reaches at least 10% and 90% V_{CC} at the specified toggle frequency.

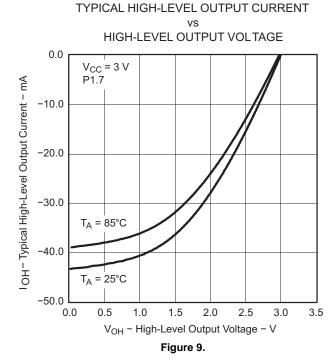


Typical Characteristics – Outputs









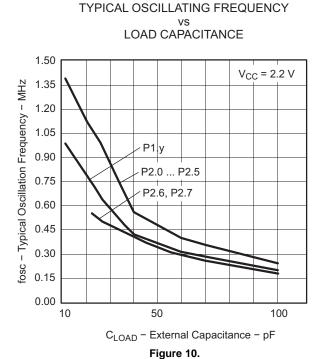
Pin-Oscillator Frequency – Ports Px

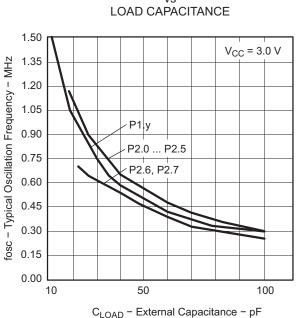
over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN TYP	MAX	UNIT	
fo	Port output appillation frequency	P1.y, $C_L = 10 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1400		kHz	
fo _{P1.x}	Port output oscillation frequency	P1.y, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	900			
40	Dort output assillation frequency	P2.0 to P2.5, $C_L = 10 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	2.1/	1800		kHz	
fo _{P2.x}	Port output oscillation frequency	P2.0 to P2.5, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1000			
fo _{P2.6/7}	Port output oscillation frequency	P2.6 and P2.7, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	700		kHz	

- A resistive divider with two 100-kΩ resistors between V_{CC} and V_{SS} is used as load. The output is connected to the center tap of the divider.
- (2) The output voltage oscillates with a typical amplitude of 700 mV at the specified toggle frequency.

Typical Characteristics – Pin-Oscillator Frequency





TYPICAL OSCILLATING FREQUENCY



POR/Brownout Reset (BOR)⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP	MAX	UNIT
V _{CC(start)}	See Figure 12	dV _{CC} /dt ≤ 3 V/s		$0.7 \times V_{(B_IT-)}$		V
$V_{(B_IT-)}$	See Figure 12 through Figure 14	dV _{CC} /dt ≤ 3 V/s		1.40		V
V _{hys(B_IT-)}	See Figure 12	dV _{CC} /dt ≤ 3 V/s		140		mV
t _{d(BOR)}	See Figure 12				2000	μs
t _(reset)	Pulse length needed at RST/NMI pin to accepted reset internally		2.2 V	2		μs

The current consumption of the brownout module is already included in the I_{CC} current consumption data. The voltage level V_(B_IT-) + V_{hys(B_IT-)}is ≤ 1.8 V.

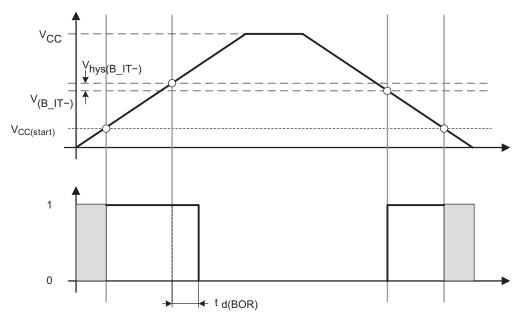


Figure 12. POR/Brownout Reset (BOR) vs Supply Voltage



Typical Characteristics - POR/Brownout Reset (BOR)

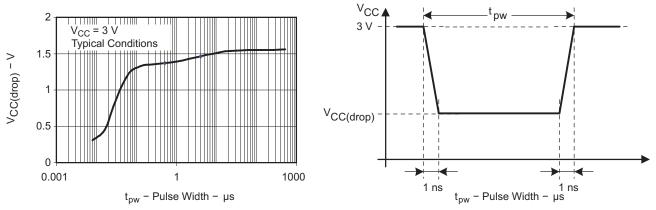


Figure 13. V_{CC(drop)} Level With a Square Voltage Drop to Generate a POR/Brownout Signal

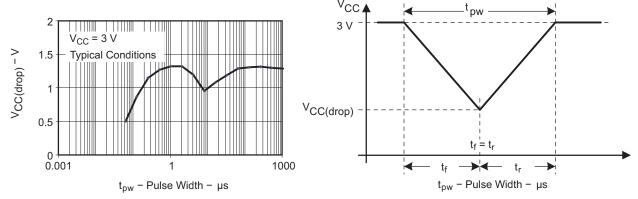


Figure 14. V_{CC(drop)} Level With a Triangle Voltage Drop to Generate a POR/Brownout Signal



DCO Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
		RSELx < 14		1.8		3.6	V
V _{CC}	Supply voltage	RSELx = 14		2.2		3.6	V
		RSELx = 15		3		3.6	V
f _{DCO(0,0)}	DCO frequency (0, 0)	RSELx = 0, $DCOx = 0$, $MODx = 0$	3 V	0.06		0.14	MHz
f _{DCO(0,3)}	DCO frequency (0, 3)	RSELx = 0, $DCOx = 3$, $MODx = 0$	3 V	0.07		0.17	MHz
f _{DCO(1,3)}	DCO frequency (1, 3)	RSELx = 1, $DCOx = 3$, $MODx = 0$	3 V		0.15		MHz
f _{DCO(2,3)}	DCO frequency (2, 3)	RSELx = 2, $DCOx = 3$, $MODx = 0$	3 V		0.21		MHz
f _{DCO(3,3)}	DCO frequency (3, 3)	RSELx = 3, $DCOx = 3$, $MODx = 0$	3 V		0.30		MHz
f _{DCO(4,3)}	DCO frequency (4, 3)	RSELx = 4, $DCOx = 3$, $MODx = 0$	3 V		0.41		MHz
f _{DCO(5,3)}	DCO frequency (5, 3)	RSELx = 5, $DCOx = 3$, $MODx = 0$	3 V		0.58		MHz
f _{DCO(6,3)}	DCO frequency (6, 3)	RSELx = 6, $DCOx = 3$, $MODx = 0$	3 V	0.54		1.06	MHz
f _{DCO(7,3)}	DCO frequency (7, 3)	RSELx = 7, $DCOx = 3$, $MODx = 0$	3 V	0.80		1.50	MHz
f _{DCO(8,3)}	DCO frequency (8, 3)	RSELx = 8, $DCOx = 3$, $MODx = 0$	3 V		1.6		MHz
f _{DCO(9,3)}	DCO frequency (9, 3)	RSELx = 9, $DCOx = 3$, $MODx = 0$	3 V		2.3		MHz
f _{DCO(10,3)}	DCO frequency (10, 3)	RSELx = 10, $DCOx = 3$, $MODx = 0$	3 V		3.4		MHz
f _{DCO(11,3)}	DCO frequency (11, 3)	RSELx = 11, $DCOx = 3$, $MODx = 0$	3 V		4.25		MHz
f _{DCO(12,3)}	DCO frequency (12, 3)	RSELx = 12, $DCOx = 3$, $MODx = 0$	3 V	4.30		7.30	MHz
f _{DCO(13,3)}	DCO frequency (13, 3)	RSELx = 13, $DCOx = 3$, $MODx = 0$	3 V	6.00		9.60	MHz
f _{DCO(14,3)}	DCO frequency (14, 3)	RSELx = 14, DCOx = 3, MODx = 0	3 V	8.60		13.9	MHz
f _{DCO(15,3)}	DCO frequency (15, 3)	RSELx = 15, $DCOx = 3$, $MODx = 0$	3 V	12.0		18.5	MHz
f _{DCO(15,7)}	DCO frequency (15, 7)	RSELx = 15, $DCOx = 7$, $MODx = 0$	3 V	16.0		26.0	MHz
S _{RSEL}	Frequency step between range RSEL and RSEL+1	$S_{RSEL} = f_{DCO(RSEL+1,DCO)}/f_{DCO(RSEL,DCO)}$	3 V		1.35		ratio
S _{DCO}	Frequency step between tap DCO and DCO+1	$S_{DCO} = f_{DCO(RSEL,DCO+1)}/f_{DCO(RSEL,DCO)}$	3 V		1.08		ratio
Duty cycle		Measured at SMCLK output	3 V		50		%

26

Calibrated DCO Frequencies – Tolerance

PARAMETER	TEST CONDITIONS	T _A	V _{cc}	MIN	TYP	MAX	UNIT
1-MHz tolerance over temperature ⁽¹⁾	BCSCTL1= CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
1-MHz tolerance over V _{CC}	BCSCTL1= CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	30°C	1.8 V to 3.6 V	-3	±2	+3	%
1-MHz tolerance overall	BCSCTL1= CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	1.8 V to 3.6 V	-6	±3	+6	%
8-MHz tolerance over temperature ⁽¹⁾	BCSCTL1= CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
8-MHz tolerance over V _{CC}	BCSCTL1= CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	30°C	2.2 V to 3.6 V	-3	±2	+3	%
8-MHz tolerance overall	BCSCTL1= CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	2.2 V to 3.6 V	-6	±3	+6	%
12-MHz tolerance over temperature ⁽¹⁾	BCSCTL1= CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
12-MHz tolerance over V _{CC}	BCSCTL1= CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	30°C	2.7 V to 3.6 V	-3	±2	+3	%
12-MHz tolerance overall	BCSCTL1= CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	2.7 V to 3.6 V	-6	±3	+6	%
16-MHz tolerance over temperature ⁽¹⁾	BCSCTL1= CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3.3 V	-3	±0.5	+3	%
16-MHz tolerance over V _{CC}	BCSCTL1= CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	30°C	3.3 V to 3.6 V	-3	±2	+3	%
16-MHz tolerance overall	BCSCTL1= CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	3.3 V to 3.6 V	-6	±3	+6	%

⁽¹⁾ This is the frequency change from the measured frequency at 30°C over temperature.



Wake-Up From Lower-Power Modes (LPM3/4)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	0 117		,		,		
	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
t _{DCO,LPM3/4}	DCO clock wake-up time from LPM3/4 ⁽¹⁾	BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ	3 V		1.5		μs
t _{CPU,LPM3/4}	CPU wake-up time from LPM3/4 ⁽²⁾			t	1/f _{MCLK} + Clock,LPM3/4		

⁽¹⁾ The DCO clock wake-up time is measured from the edge of an external wake-up signal (for example, a port interrupt) to the first clock edge observable externally on a clock pin (MCLK or SMCLK).

Typical Characteristics - DCO Clock Wake-Up Time From LPM3/4

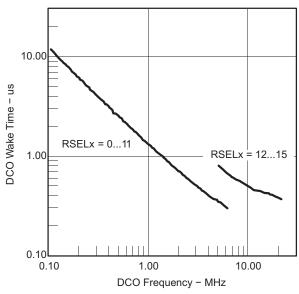


Figure 15. DCO Wake-Up Time From LPM3 vs DCO Frequency

⁽²⁾ Parameter applicable only if DCOCLK is used for MCLK.



Crystal Oscillator, XT1, Low-Frequency Mode⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{LFXT1,LF}	LFXT1 oscillator crystal frequency, LF mode 0, 1	XTS = 0, LFXT1Sx = 0 or 1	1.8 V to 3.6 V		32768		Hz
f _{LFXT1,LF,logic}	LFXT1 oscillator logic level square wave input frequency, LF mode	XTS = 0, XCAPx = 0, LFXT1Sx = 3	1.8 V to 3.6 V	10000	32768	50000	Hz
04	Oscillation allowance for	XTS = 0, LFXT1Sx = 0, f _{LFXT1,LF} = 32768 Hz, C _{L,eff} = 6 pF			500		kΩ
OA _{LF}	LF crystals	$XTS = 0$, $LFXT1Sx = 0$, $f_{LFXT1,LF} = 32768$ Hz, $C_{L,eff} = 12$ pF			200		K12
		XTS = 0, $XCAPx = 0$			1		
0	Integrated effective load	XTS = 0, $XCAPx = 1$			5.5		~F
$C_{L,eff}$	capacitance, LF mode (2)	XTS = 0, $XCAPx = 2$			8.5		pF
		XTS = 0, XCAPx = 3		11			† '
Duty cycle	LF mode	XTS = 0, Measured at P2.0/ACLK, f _{LFXT1,LF} = 32768 Hz	2.2 V	30	50	70	%
f _{Fault,LF}	Oscillator fault frequency, LF mode ⁽³⁾	XTS = 0, XCAPx = 0, LFXT1Sx = 3 ⁽⁴⁾	2.2 V	10		10000	Hz

- (1) To improve EMI on the XT1 oscillator, the following guidelines should be observed.
 - (a) Keep the trace between the device and the crystal as short as possible.
 - (b) Design a good ground plane around the oscillator pins.
 - (c) Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
 - (d) Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
 - (e) Use assembly materials and praxis to avoid any parasitic load on the oscillator XIN and XOUT pins.
 - (f) If conformal coating is used, ensure that it does not induce capacitive/resistive leakage between the oscillator pins.
 - (g) Do not route the XOUT line to the JTAG header to support the serial programming adapter as shown in other documentation. This signal is no longer required for the serial programming adapter.
- (2) Includes parasitic bond and package capacitance (approximately 2 pF per pin).
 - Because the PCB adds additional capacitance, it is recommended to verify the correct load by measuring the ACLK frequency. For a correct setup, the effective load capacitance should always match the specification of the used crystal.
- (3) Frequencies below the MIN specification set the fault flag. Frequencies above the MAX specification do not set the fault flag. Frequencies in between might set the flag.
- (4) Measured with logic-level input frequency but also applies to operation with crystals.

Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	T _A	V _{cc}	MIN	TYP	MAX	UNIT
f_{VLO}	VLO frequency ⁽¹⁾	-40°C to 85°C	3 V	4	12	20	kHz
df_{VLO}/d_{T}	VLO frequency temperature drift	-40°C to 85°C	3 V		0.5		%/°C
df_{VLO}/dV_{CC}	VLO frequency supply voltage drift	25°C	1.8 V to 3.6 V		4		%/V

⁽¹⁾ Ensured by design on specified temperature.

Timer A

PARAMETER		TEST CONDITIONS		MIN TYP MAX	UNIT
f _{TA}	Timer_A input clock frequency	SMCLK Duty cycle = 50% ± 10%		f _{SYSTEM}	MHz
t _{TA,cap}	Timer_A capture timing	TA0, TA1	3 V	20	ns

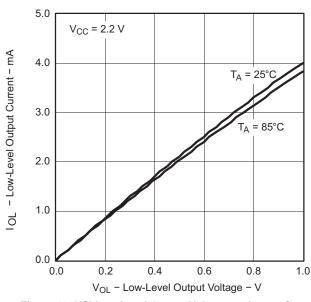


USI, Universal Serial Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS V _{CC}		MIN TYP	MAX	UNIT
f _{USI}	USI module clock frequency	External: SCLK, Duty cycle = 50% ± 10%		f _{SYSTE}	М	MHz
f _(SCLK)	Serial clock frequency, slave mode	SPI slave mode	3 V		6	MHz
V _{OL,I2C}	Low-level output voltage on SDA and SCL	USI module in I2C mode, I _(OLmax) = 1.5 mA	3 V	V _{SS}	V _{SS} + 0.4	V

Typical Characteristics – USI Low-Level Output Voltage on SDA and SCL



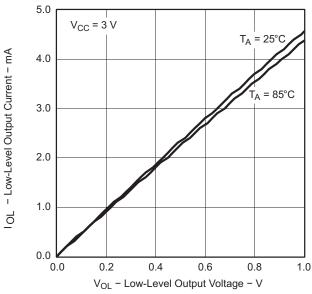


Figure 16. USI Low-Level Output Voltage vs Output Current

Figure 17. USI Low-Level Output Voltage vs Output Current

Flash Memory

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
V _{CC(PGM/ERASE)}	Program and erase supply voltage			2.2		3.6	V
f _{FTG}	Flash timing generator frequency			257		476	kHz
I _{PGM}	Supply current from V _{CC} during program		2.2 V, 3.6 V		1	5	mA
I _{ERASE}	Supply current from V _{CC} during erase		2.2 V, 3.6 V		1	7	mA
t _{CPT}	Cumulative program time ⁽¹⁾		2.2 V, 3.6 V			10	ms
t _{CMErase}	Cumulative mass erase time		2.2 V, 3.6 V	20			ms
	Program and erase endurance			10 ⁴	10 ⁵		cycles
t _{Retention}	Data retention duration	T _J = 25°C		100			years
t _{Word}	Word or byte program time	See (2)			30		t _{FTG}
t _{Block, 0}	Block program time for first byte or word	See (2)			25		t _{FTG}
t _{Block, 1-63}	Block program time for each additional byte or word	See (2)			18		t _{FTG}
t _{Block, End}	Block program end-sequence wait time	See (2)			6		t _{FTG}
t _{Mass Erase}	Mass erase time	See (2)			10593		t _{FTG}

⁽¹⁾ The cumulative program time must not be exceeded when writing to a 64-byte flash block. This parameter applies to all programming methods: individual word or byte write mode and block write mode.

⁽²⁾ These values are hardwired into the flash controller's state machine ($t_{FTG} = 1/f_{FTG}$).



SLAS868A -JUNE 2012-REVISED NOVEMBER 2012

Flash Memory (continued)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
t _{Seg Erase}	Segment erase time	See (2)			4819		t _{FTG}



RAM

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN MAX	UNIT
V _(RAMh)	RAM retention supply voltage (1)	CPU halted	1.6	V

⁽¹⁾ This parameter defines the minimum supply voltage V_{CC} when the data in RAM remains unchanged. No program execution should happen during this supply voltage condition.

JTAG and Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT	
f _{SBW}	Spy-Bi-Wire input frequency		2.2 V	0		20	MHz	
t _{SBW,Low}	Spy-Bi-Wire low clock pulse length		2.2 V	0.025		15	μs	
t _{SBW,En}	Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge (1))		2.2 V			1	μs	
t _{SBW,Ret}	Spy-Bi-Wire return to normal operation time		2.2 V	15		100	μs	
f _{TCK}	TCK input frequency ⁽²⁾		2.2 V	0		5	MHz	
R _{Internal}	Internal pulldown resistance on TEST		2.2 V	25	60	90	kΩ	

⁽¹⁾ Tools accessing the Spy-Bi-Wire interface need to wait for the maximum t_{SBW,En} time after pulling the TEST/SBWCLK pin high before applying the first SBWCLK clock edge.

JTAG Fuse⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
V _{CC(FB)}	Supply voltage during fuse-blow condition	T _A = 25°C	2.5		V
V_{FB}	Voltage level on TEST for fuse blow		6	7	V
I _{FB}	Supply current into TEST during fuse blow			100	mA
t _{FB}	Time to blow fuse			1	ms

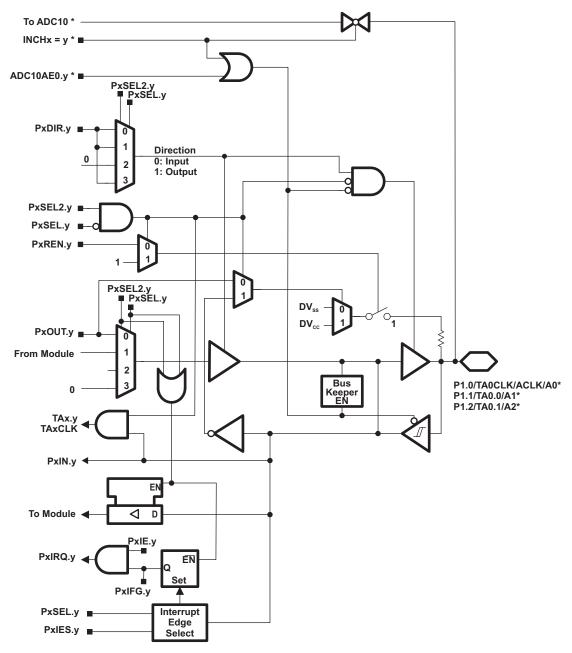
(1) Once the fuse is blown, no further access to the JTAG/Test, Spy-Bi-Wire, and emulation feature is possible, and JTAG is switched to bypass mode.

⁽²⁾ f_{TCK} may be restricted to meet the timing requirements of the module selected.



PIN SCHEMATICS

Port P1 Pin Schematic: P1.0 to P1.2, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x32 devices only. MSP430G2x02 devices have no ADC10.



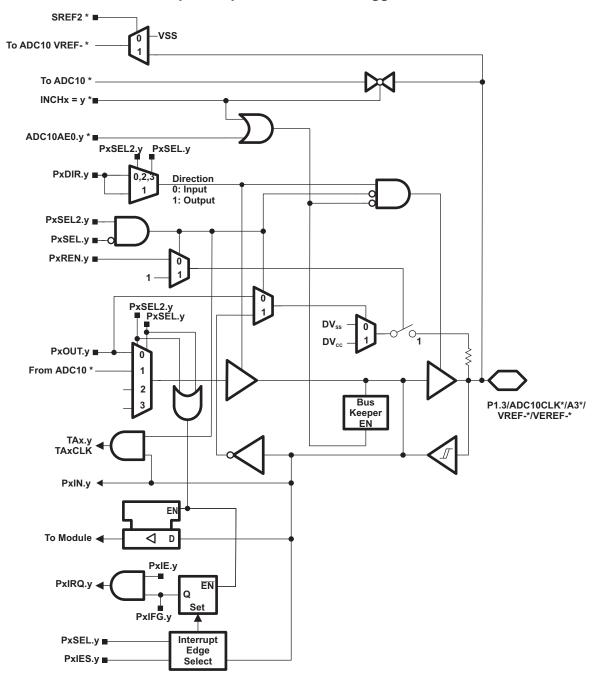
Table 15. Port P1 (P1.0 to P1.2) Pin Functions

DIN NAME (D4 v)		FUNCTION	CON	CONTROL BITS / SIGNALS ⁽¹⁾			
PIN NAME (P1.x)	х		P1DIR.x	P1SEL.x	P1SEL2.x		
P1.0/		P1.x (I/O)	I: 0; O: 1	0	0		
TA0CLK/	0	TA0.TACLK	0	1	0		
ACLK/		ACLK	1	1	0		
Pin Osc		Capacitive sensing	х	0	1		
P1.1/		P1.x (I/O)	I: 0; O: 1	0	0		
TA0.0/	1	TA0.0	1	1	0		
		TA0.CCI0A	0	1	0		
Pin Osc		Capacitive sensing	X	0	1		
P1.2/		P1.x (I/O)	I: 0; O: 1	0	0		
TA0.1/	2	TA0.1	1	1	0		
		TA0.CCI1A	0	1	0		
Pin Osc		Capacitive sensing	X	0	1		

⁽¹⁾ X = don't care



Port P1 Pin Schematic: P1.3, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x32 devices only. MSP430G2x02 devices have no ADC10.



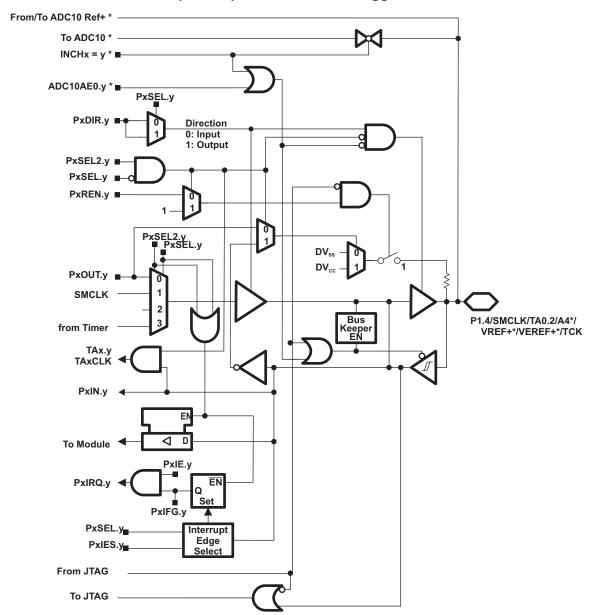
Table 16. Port P1 (P1.3) Pin Functions

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS / SIGNALS ⁽¹⁾				
			P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x (INCH.x=1)	
P1.3/		P1.x (I/O)	I: 0; O: 1	0	0	0	
ADC10CLK/		ADC10CLK	1	1	0	0	
A3/	3	A3	X	X	X	1 (y = 3)	
VREF-/	3	VREF-	X	X	Х	1	
VEREF-/		VEREF-	Х	Х	Х	1	
Pin Osc		Capacitive sensing	X	0	1	0	

⁽¹⁾ X = don't care



Port P1 Pin Schematic: P1.4, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x32 devices only. MSP430G2x02 devices have no ADC10.



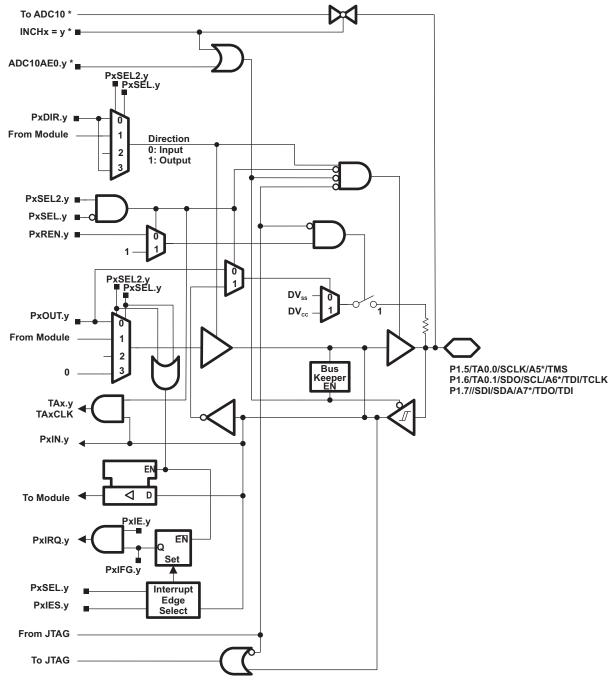
Table 17. Port P1 (P1.4) Pin Functions

	x			CONTROL BITS / SIGNALS ⁽¹⁾									
PIN NAME (P1.x)		FUNCTION	P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x (INCH.x=1)	JTAG Mode						
P1.4/		P1.x (I/O)	I: 0; O: 1	0	0	0	0						
SMCLK/		SMCLK	1	1	0	0	0						
TA0.2/		TA0.2	1	1	1	0	0						
		TA0.CCI2A	0	1	1	0	0						
VREF+/	4	VREF+	X	Х	X	1	0						
VEREF+/		VEREF+	Х	Х	X	1	0						
A4/			A4	X	Х	X	1 (y = 4)	0					
TCK/		тск	Х	Х	Х	0	1						
Pin Osc		Capacitive sensing	X	0	1	0	0						

⁽¹⁾ X = don't care



Port P1 Pin Schematic: P1.5 to P1.7, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x32 devices only. MSP430G2x02 devices have no ADC10.



Table 18. Port P1 (P1.5 to P1.7) Pin Functions

PIN NAME (P1.x)			CONTROL BITS / SIGNALS ⁽¹⁾									
	x	FUNCTION	P1DIR.x	P1SEL.x	P1SEL2.x	USIP.x	JTAG Mode	ADC10AE.x (INCH.x=1)				
P1.5/		P1.x (I/O)	I: 0; O: 1	0	0	0	0	0				
TA0.0/		TA0.0	1	1	0	0	0	0				
SCLK/	_	SPI mode	from USI	1	0	1	0	0				
A5/	5	A5	Х	Х	Х	0	0	1 (y = 5)				
TMS/		TMS	Х	Х	Х	0	1	0				
Pin Osc		Capacitive sensing	Х	0	1	0	0	0				
P1.6/		P1.x (I/O)	I: 0; O: 1	0	0	0	0	0				
TA0.1/		TA0.1	1	1	0	0	0	0				
SDO/		SPI mode	from USI	1	0	ļ.	0	0				
SCL/	6	I2C mode	from USI	1	0	!	0	0				
A6/		A6	Х	Х	Х	0	0	1 (y = 6)				
TDI/TCLK/		TDI/TCLK	Х	Х	Х	0	1	0				
Pin Osc		Capacitive sensing	Х	0	1	0	0	0				
P1.7/		P1.x (I/O)	I: 0; O: 1	0	0	0	0	0				
SDI/		SPI mode	from USI	1	0	1	0	0				
SDA/	7	SPI mode from USI		1	0	1	0	0				
A7/	/	A7	Х	Х	Х	0	0	1 (y = 7)				
TDO/TDI/		TDO/TDI X X		Х	Х	0	1	0				
Pin Osc		Capacitive sensing	Х	0	1	0	0	0				

⁽¹⁾ X = don't care



Port P2 Pin Schematic: P2.0 to P2.5, Input/Output With Schmitt Trigger

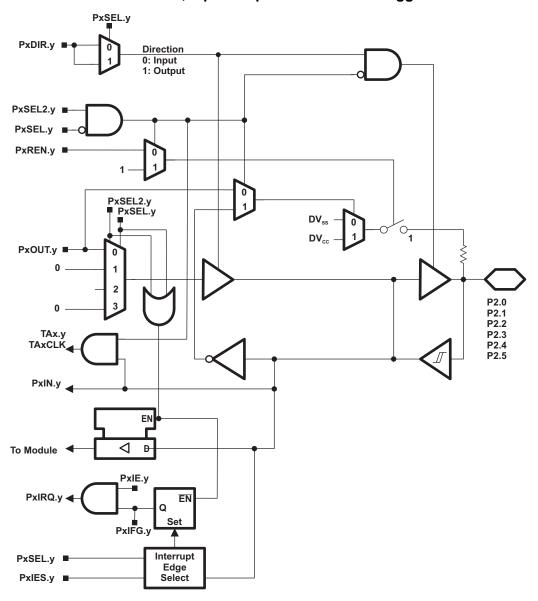




Table 19. Port P2 (P2.0 to P2.5) Pin Functions

PIN NAME (P2.x)		FUNCTION	CONTROL BITS / SIGNALS ⁽¹⁾			
	х	FUNCTION	P2DIR.x	P2SEL.x	P2SEL2.x	
P2.0/	0	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	U	Capacitive sensing	Х	0	1	
P2.1/	1	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	'	Capacitive sensing	Х	0	1	
P2.2/	2	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	2	Capacitive sensing	Х	0	1	
P2.3/	3	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	3	Capacitive sensing	Х	0	1	
P2.4/	4	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	4	Capacitive sensing	Х	0	1	
P2.5/	_	P2.x (I/O)	I: 0; O: 1	0	0	
Pin Osc	5	Capacitive sensing	Х	0	1	

⁽¹⁾ X = don't care



Port P2 Pin Schematic: P2.6, Input/Output With Schmitt Trigger

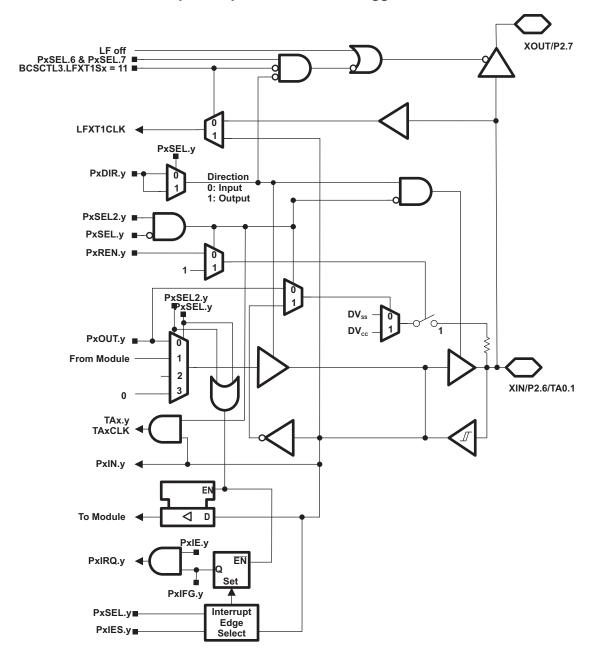


Table 20. Port P2 (P2.6) Pin Functions

PIN NAME (P2.x)	x		CONTROL BITS / SIGNALS ⁽¹⁾			
		FUNCTION	P2DIR.x	P2SEL.6 P2SEL.7	P2SEL2.6 P2SEL2.7	
XIN/		XIN	0	1 1	0	
P2.6/		P2.x (I/O)	I: 0; O: 1	0 X	0	
TA0.1/	6	Timer0_A3.TA1	1	1 0	0	
Pin Osc		Capacitive sensing	Х	0 X	1 X	

(1) X = don't care



Port P2 Pin Schematic: P2.7, Input/Output With Schmitt Trigger

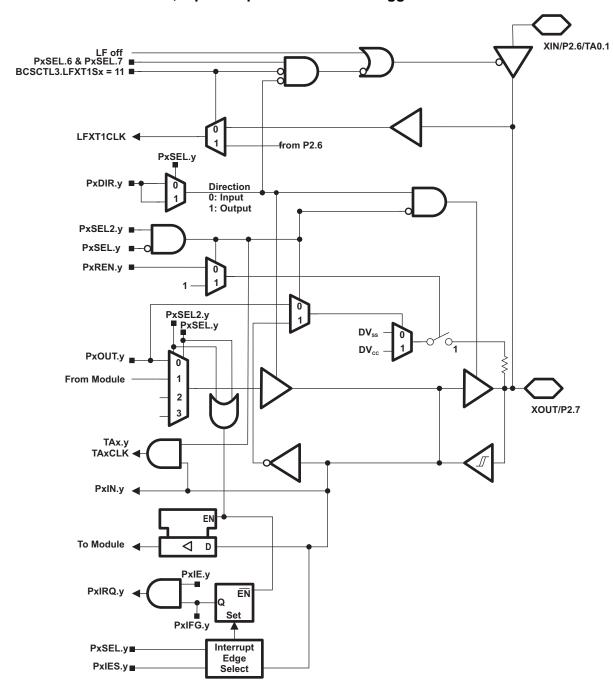


Table 21. Port P2 (P2.7) Pin Functions

PIN NAME			CONTROL BITS / SIGNALS ⁽¹⁾			
(P2.x)	x	FUNCTION	P2DIR.x	P2SEL.6 P2SEL.7	P2SEL2.6 P2SEL2.7	
XOUT/		XOUT	х	1 1	0 0	
P2.7/	7	P2.x (I/O)	I: 0; O: 1	X 0	0	
Pin Osc		Capacitive sensing	Х	X 0	X 1	

(1) X = don't care





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
MSP430G2302IPW1EP	ACTIVE	TSSOP	PW	14	90	TBD	Call TI	Call TI	-40 to 85	G2302EP	Samples
MSP430G2302IPW1REP	ACTIVE	TSSOP	PW	14	2000	TBD	Call TI	Call TI	-40 to 85	G2302EP	Samples
V62/12623-01XE	ACTIVE	TSSOP	PW	14	2000	TBD	Call TI	Call TI	-40 to 85	G2302EP	Samples
V62/12623-01XE-T	ACTIVE	TSSOP	PW	14	90	TBD	Call TI	Call TI	-40 to 85	G2302EP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



PACKAGE OPTION ADDENDUM

11-Apr-2013

OTHER QUALIFIED VERSIONS OF MSP430G2302-EP:

● Catalog: MSP430G2302

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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